International **IOR** Rectifier

PD-91800

IR2153Z

Features

- Floating channel designed for bootstrap operation Fully operational to +600V
 Tolerant to negative transient voltage dV/dt immune
- · Undervoltage lockout
- · Programmable oscillator frequency

 $f = \frac{1}{1.4 \times (\mathsf{R}_{\mathsf{T}} + 75\Omega) \times \mathsf{C}_{\mathsf{T}}}$

- · Matched propagation delay for both channels
- Micropower supply startup current of 90 µA.
- Shutdown function turns off both channels
- · Low side output in phase with RT

Description

The IR2153Z is a high voltage, high speed, self-oscillating power MOSFET and IGBT driver with both high and low side referenced output channels. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. The front end features a programmable oscillator which is similar to the 555 timer. The output drivers feature a high pulse current buffer stage and

SELF-OSCILLATING HALF-BRIDGE DRIVER

Product Summary

VOFFSET	600V max.
Duty Cycle	50%
I _O +/-	200 mA / 400 mA
V _{clamp}	15.6V
Deadtime (typ.)	1.2 µs

an internal deadtime designed for minimum driver crossconduction. Propagation delays for the two channels are matched to simplify use in 50% duty cycle applications. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high side configuration that operates off a high voltage rail up to 600 volts.

Absolute Maximum Ratings

Absolute Maximum Ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The Thermal Resistance and Power Dissipation ratings are measured under board mounted and still air conditions.

Symbol	Parameter	Min.	Max.	Units
VB	High Side Floating Supply Voltage	-0.3	625	
VS	High Side Floating Supply Offset Voltage	V _B - 25	V _B + 0.3	
V _{HO}	High Side Floating Output Voltage	V _S - 0.3	V _B + 0.3	
VLO	Low Side Output Voltage	-0.3	V _{CC} + 0.3	V
V _{RT}	R _T Voltage	-0.3	V _{CC} + 0.3	Ī
V _{CT}	C _T Voltage	-0.3	V _{CC} + 0.3	
ICC	Supply Current (Note 1)	—	25	
I _{RT}	R _T Output Current	-5	5	mA
dV _s /dt	Allowable Offset Supply Voltage Transient	—	50	V/ns
PD	Package Power Dissipation @ T _{A £} +25°C	—	1.0	W
RthJA	Thermal Resistance, Junction to Ambient	—	100	°C/W
ТJ	Junction Temperature	-55	125	
Τ _S	Storage Temperature	-55	150	٦°
TL	Lead Temperature (Soldering, 10 seconds)	_	300	

Recommended Operating Conditions

The Input/Output logic timing diagram is shown in Figure 1. For proper operation the device should be used within the recommended conditions. The V_S offset rating is tested with all supplies biased at 15V differential.

Symbol	Definition	Min.	Max.	Units
VB	High Side Floating Supply Absolute Voltage	V _S + 10	V _S + 20	
Vs	High Side Floating Supply Offset Voltage	_	600	
V _{HO}	High Side Floating Output Voltage	Vs	VB	
V _{LO}	Low Side Output Voltage	0	V _{CC}	
ICC	Supply Current (Note 1)	—	5	mA

Dynamic Electrical Characteristics

 V_{BIAS} (V_{CC}, V_{BS}) = 12V, C_L = 1000 pF and T_A = 25°C unless otherwise specified.

Symbol	Definition	Min.	Тур.	Max.	Units	Test Conditions
tr	Turn-On Rise Time	—	80	165		
t _f	Turn-Off Fall Time	—	35	100	ns	
t _{sd}	Shutdown Propagation Delay	—	660	-		
DT	Deadtime	—	1.2	—	μs	
D	R _T Duty Cycle	—	50	—	%	



Note 1: Because of the IR2153's application specificity toward off-line supply systems, this IC contains a zener clamp structure between the chip V_{CC} and COM which has a nominal breakdown voltage of 15.6V. Therefore, the IC supply voltage is normally derived by forcing current into the supply lead (typically by means of a high value resistor connected between the chip V_{CC} and the rectified line voltage and a local decoupling capacitor from V_{CC} to COM) and allowing the internal zener clamp circuit to determine the nominal supply voltage. Therefore, this circuit should not be driven by a DC, low impedance power source of greater than V_{CLAMP}.

Static Electrical Characteristics

 V_{BIAS} (V_{CC}, V_{BS}) = 12V, C_L = 1000 pF, C_T = 1 nF and T_A = 25°C unless otherwise specified. The V_{IN}, V_{TH} and I_{IN} parameters are referenced to COM. The V_O and I_O parameters are referenced to COM and are applicable to the respective output leads: HO or LO.

Symbol	Definition	Min.	Тур.	Max.	Units	Test Conditions
fosc	Oscillator Frequency		20.0	—		R _T = 35.7 kw
		—	100	—	kHz	R _T = 7.04 kw
V _{CLAMP}	V _{CC} Zener Shunt Clamp Voltage	_	15.6	—		I _{CC} = 5 mA
V _{CT+}	2/3 V _{CC} Threshold	—	8.0	—		
V _{CT-}	1/3 V _{CC} Threshold	_	4.0	—	V	
V _{CTSD}	C _T shutdown Input Threshold		2.2	—		
V _{RT+}	R _T High Level Output Voltage, V _{CC} - R _T	_	0	100		I _{RT} = -100 μA
		—	200	300		I _{RT} = -1 mA
V _{RT-}	R _T Low Level Output Voltage	_	20	50	1	I _{RT} = 100 μA
		—	200	300	mV	I _{RT} = 1 mA
V _{OH}	High Level Output Voltage, V _{BIAS} - V _O	_	—	100		I _O = 0A
V _{OL}	Low Level Output Voltage, V _O		_	100		I _O = 0A
I _{LK}	Offset Supply Leakage Current	_	—	50		$V_B = V_S = 600V$
I _{QBS}	Quiescent V _{BS} Supply Current	_	10	—		
IQCCUV	Micropower V _{CC} Supply Startup Current	_	90	—	μA	V _{CC} < V _{CCUV}
I _{QCC}	Quiescent V _{CC} Supply Current	—	400	—		V _{CC} > V _{CCUV}
I _{CT}	C _T Input Current	_	0.001	1.0		
V _{CCUV+}	V _{CC} Supply Undervoltage Positive Going	_	9.0	—		
	Threshold				V	
V _{CCUV-}	V _{CC} Supply Undervoltage Negative Going	_	8.0	—		
	Threshold					
V _{CCUVH}	V _{CC} Supply Undervoltage Lockout Hysteresis	—	1.0	—	V	
I _{O+}	Output High Short Circuit Pulsed Current	—	200	—	mA	$V_{O} = 0V$
I ₀₋	Output Low Short Circuit Pulsed Current	—	400	—		V _O = 15V











Figure 3. Deadtime Waveform Definitions

Functional Block Diagram



Lead Definitions

Le	ad		
Symbol	Description		
R _T	Oscillator timing resistor input, in phase with HO for normal IC operation		
CT	Oscillator timing capacitor input, the oscillator frequency according to the following equation:		
	$f = \frac{1}{1.4 \times (R_{T} + 75\Omega) \times C_{T}}$		
	where 75_W is the effective impedance of the R_T output stage		
VB	High side floating supply		
НО	High side gate drive output		
VS	High side floating supply return		
Vcc	Low side and logic fixed supply		
LO	Low side gate drive output		
COM	Low side return		

IR2153Z

Case Outline and Dimensions MO-036AA



NOTES:

- 1. DIMENSIONING & TOLERANCING PER ANSI Y14.5M-1982.
- 2. CONTROLLING DIMENSION: INCH.
- 3. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].

LEAD ASSIGNMENTS

VB OUT CS VS	V _B HO V _S LO
8 7 6 5	8 7 6 5
IR2125Z	IR2153Z
1 2 3 4	1 2 3 4
V _{CC} IN ERR V _{SS}	V _{CC} R _T C _T COM



4. OUTLINE CONFORMS TO JEDEC OUTLINE MO-036AA. MEASURED WITH THE LEADS CONSTRAINED TO BE PERPENDICULAR TO DATUM PLANE C.

International

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